

# Microelectronics Structures and Devices

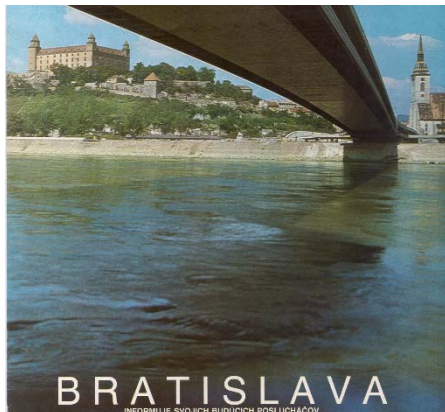
**Jaroslav Kovac & Daniel Donoval**

**Slovak University of Technology in Bratislava, Slovakia**

**Faculty of Electrical Engineering and Information Technology**

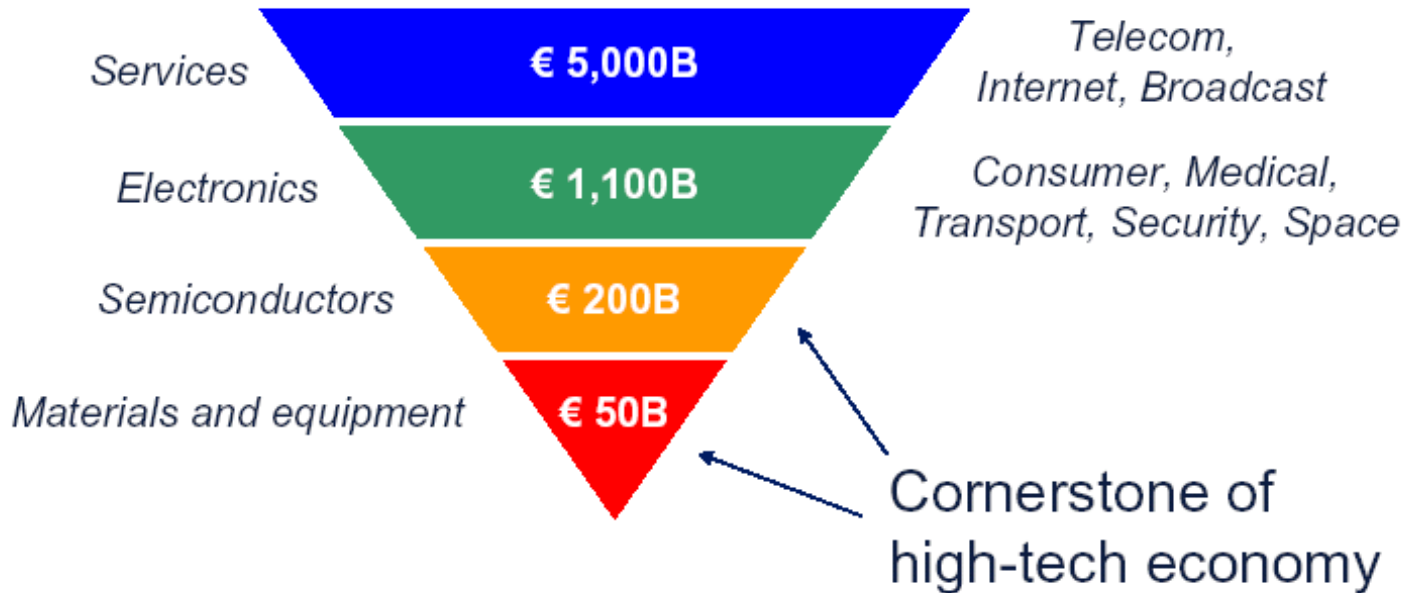
**Institute of Electronics and Photonics**

**[jaroslav.kovac@stuba.sk](mailto:jaroslav.kovac@stuba.sk)**

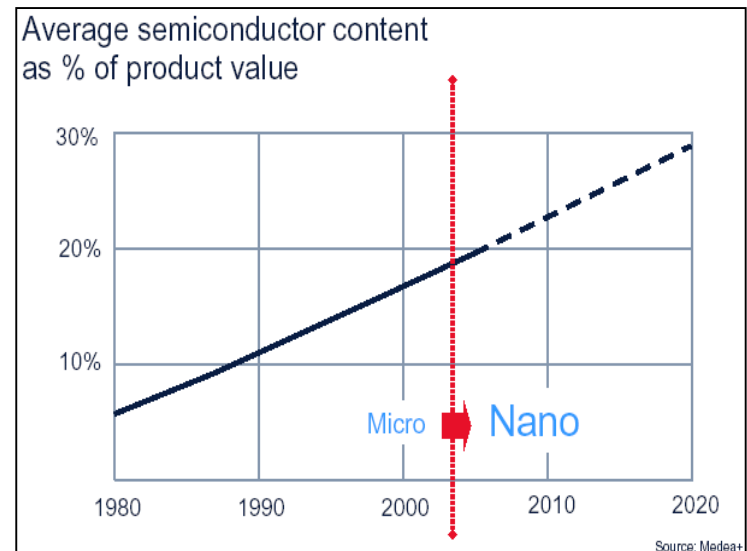


- **Introduction**
- Micro - Nanoelectronics and Photonics driving force
- New materials and technologies
- Nano-dimensions – new physical properties
- Examples of applications
- Potential and Selected Activities of Slovak University of Technology in Key Enabling Technologies
- Summary

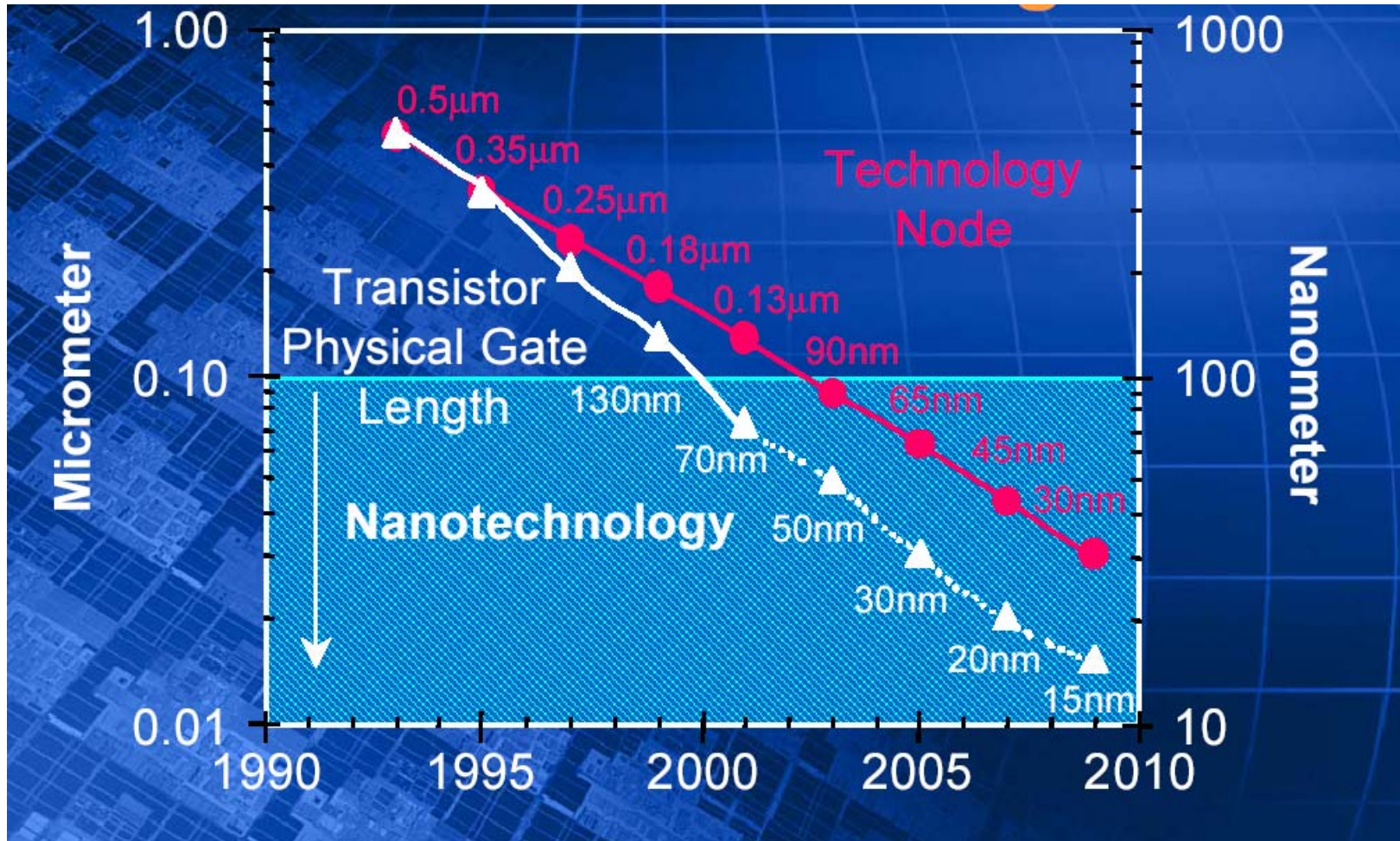
# High Tech – Economic Impact



**Micro and Nanotechnology penetrates to all industrial branches**



# Transistor scaling



**Miniaturization under 100 nm → NANOELECTRONICS**

# Nanotechnology (Nanoelectronics, Nanophotonics) Application Sectors

Medicine  
and  
Health

Information  
Technology

Energy  
Production  
/ Storage

Materials  
Science

Food, Water  
and the  
Environment

Instruments



Drug  
delivery



GMR Hard  
Disk



Hydrogen  
Fuel Cells



Lightweight  
and strong

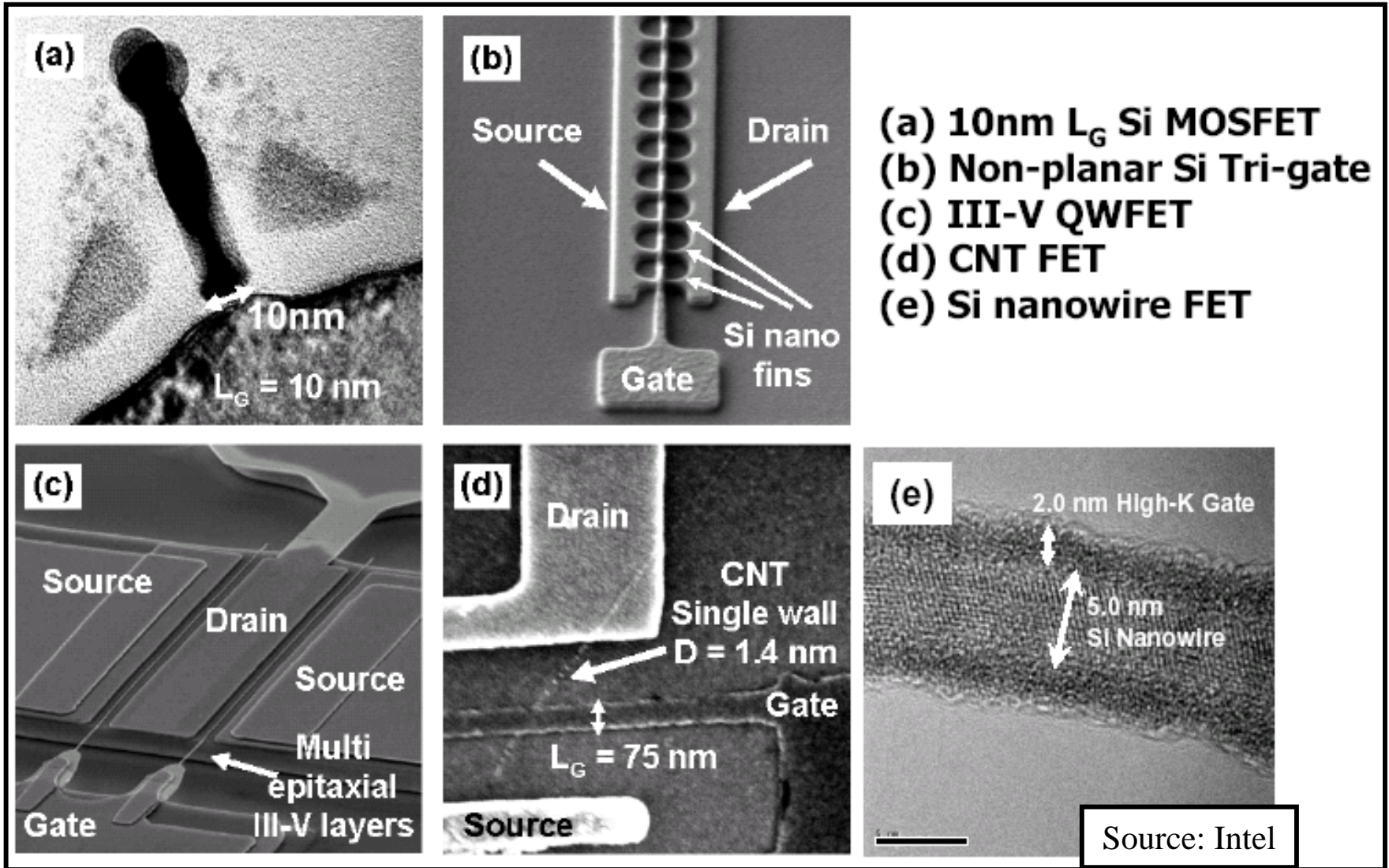


Remediation  
methods



Tunneling  
microscopy

# Emerging Nanoelectronic Devices

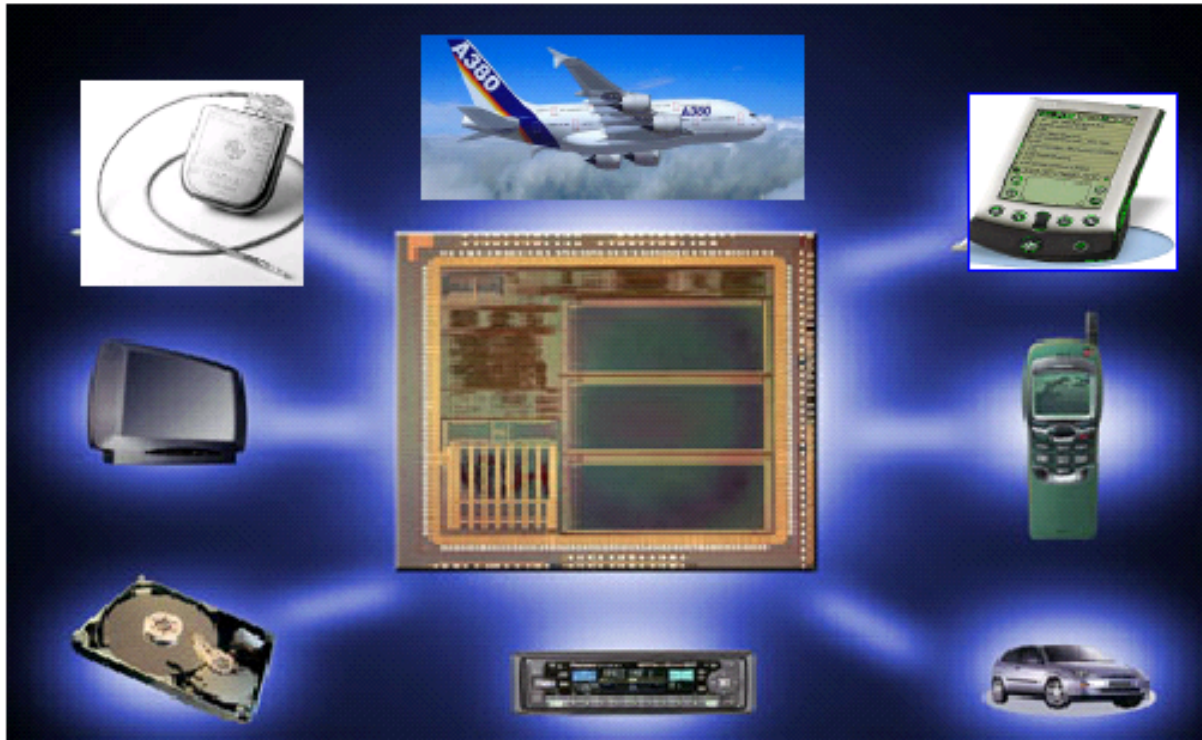


# Diversity of Microelectronics

Health

Industry

Computer



Consumer

Telecom

Data Storage

Source: MEDEA+

Automotive

More complex, faster, cheaper, higher reliability, lower consumption

# Diversity of Photonics





# Diversity of Photonics

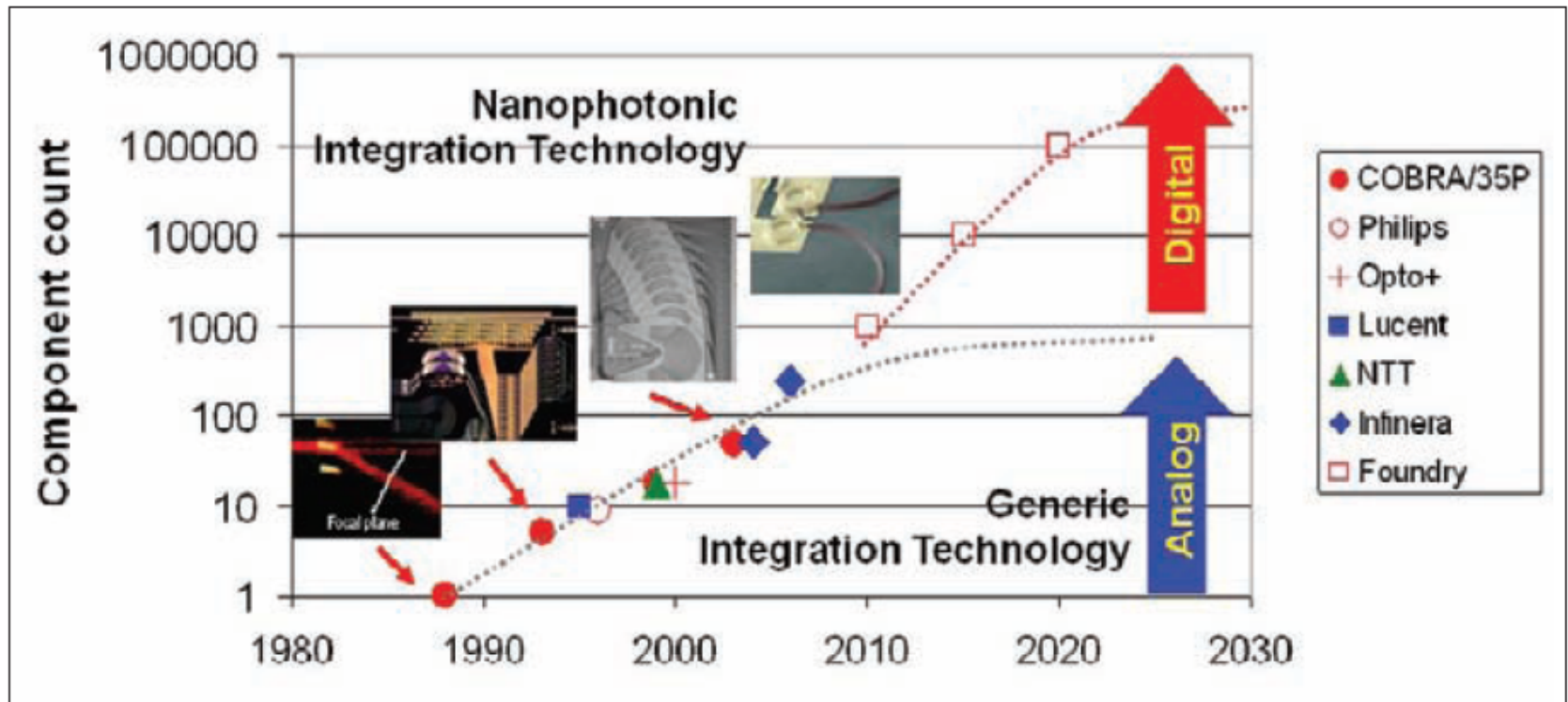
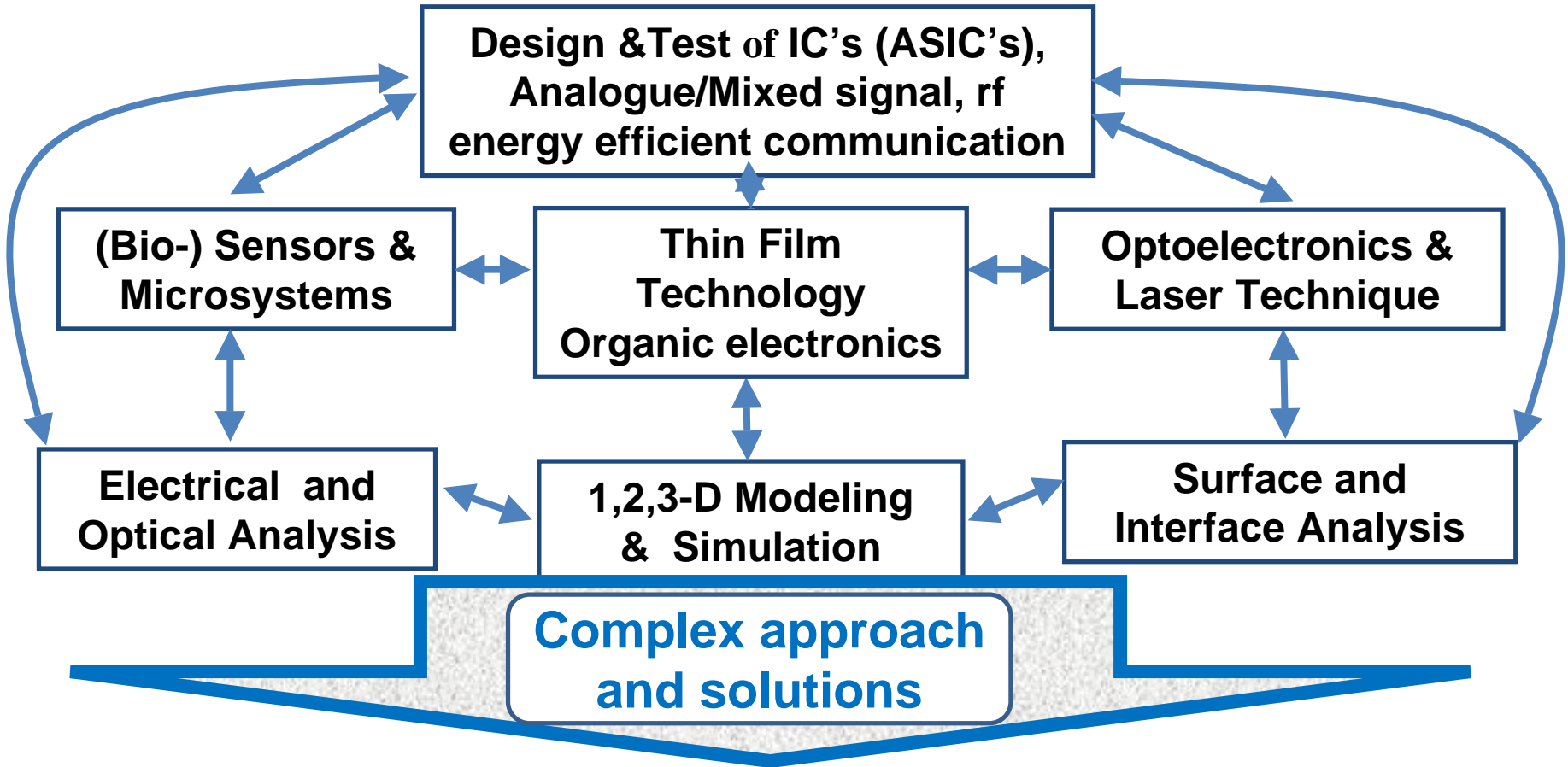


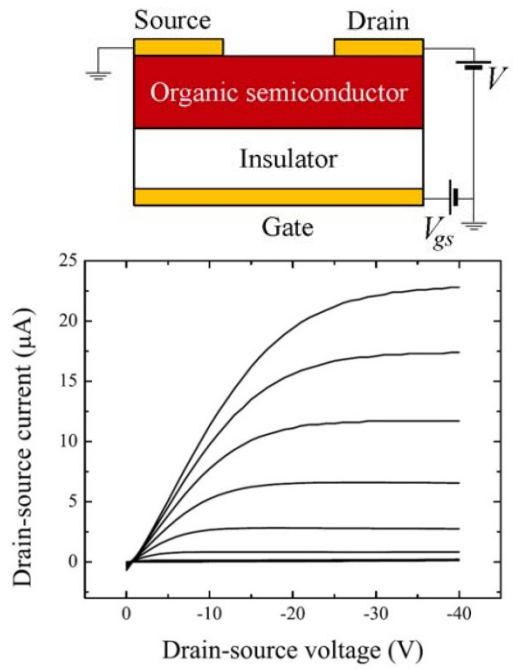
Figure 1: Roadmap shows component count versus year and rise of digitization over analog photonic integration solutions (Meint Smit, TU/e, OIDA Photonic Integration Forum, Oct 2008)

## Potential and Selected Activities of Slovak University of Technology in Key Enabling Technologies

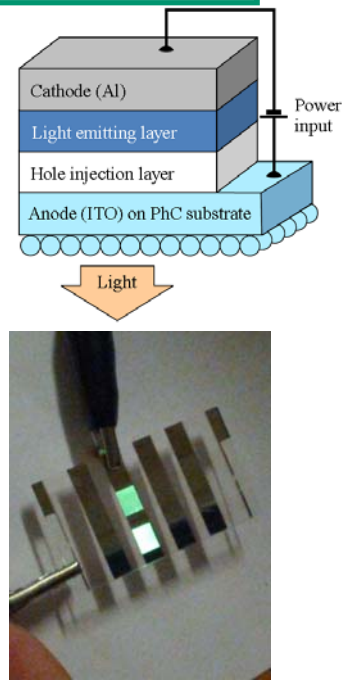


**Applications:** Signal processing, smart sensors, medical electronics, health, organic electronics, carbon nanotubes, graphen, photovoltaics, photonics

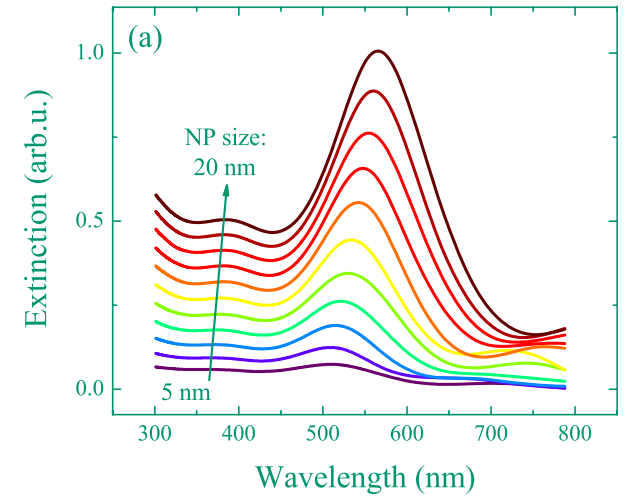
## Organic FET:



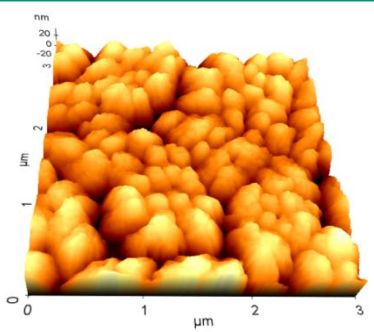
## Organic LED:



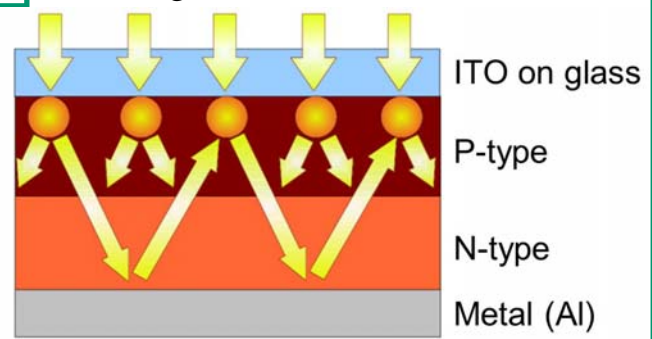
## Extinction of Plasmonic NP Monolayer



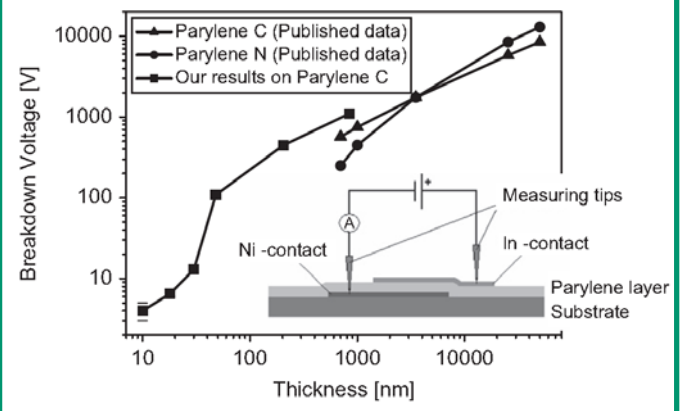
## Film structure study:



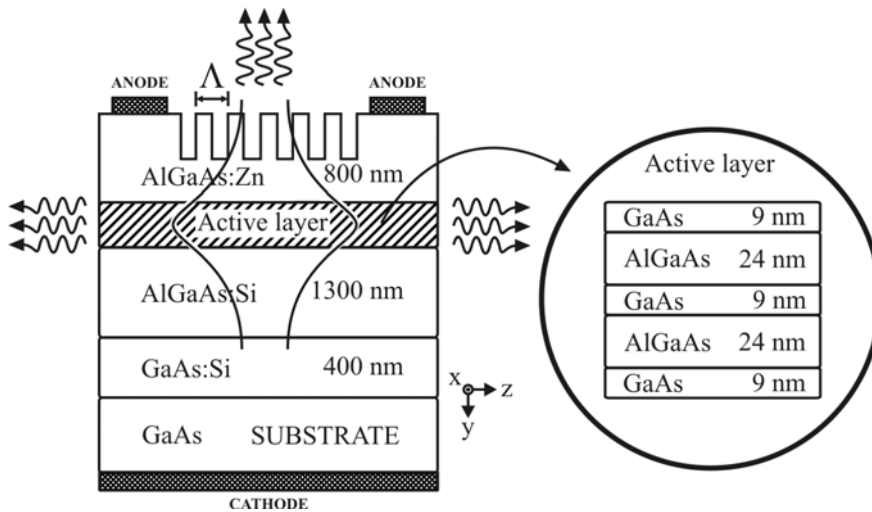
## Bare glass & NP modified surface



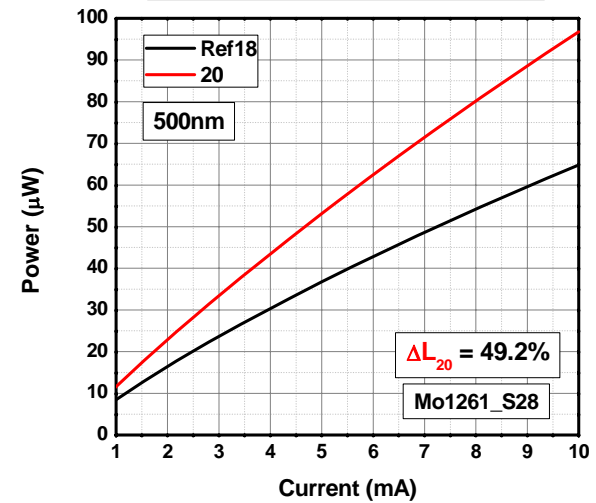
## Organic Encapsulation and Insulating Films:



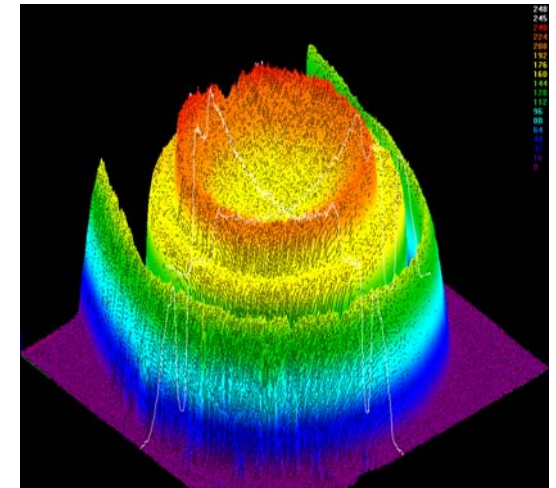
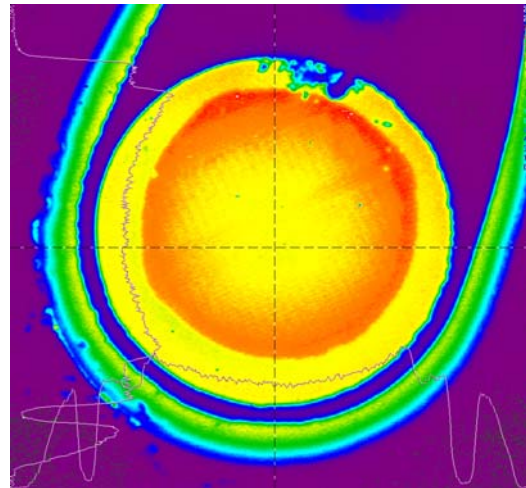
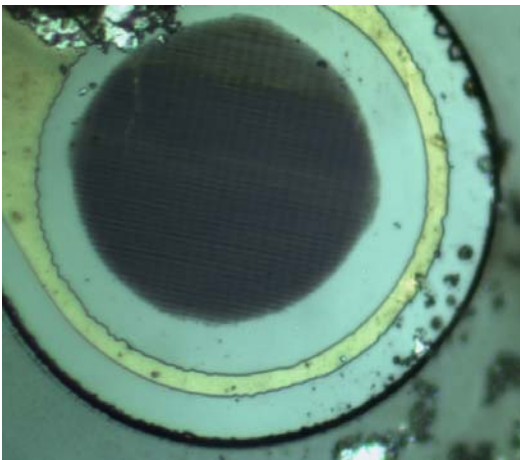
# AlGaAs/GaAs LEDs with Photonic structures patterned by EBDW lithography



1D PhC, 500 nm

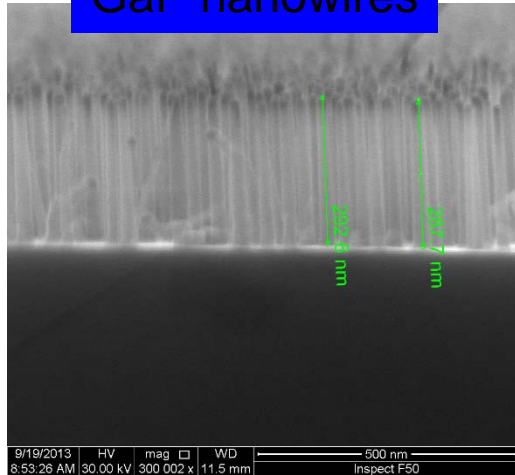


Spiricon - 1mA

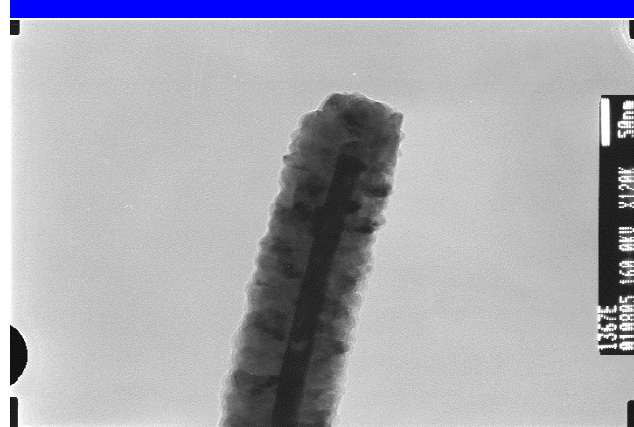


# GaP/ZnO core-shell nanowire technology

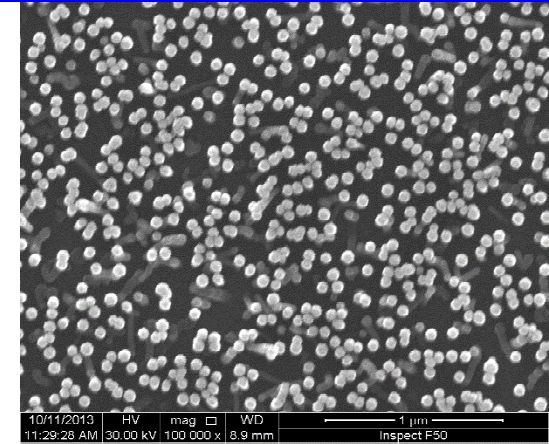
GaP nanowires



GaP nanowire + 50 nm ZnO



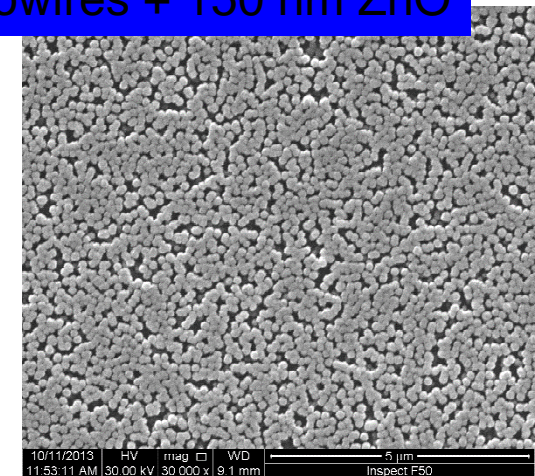
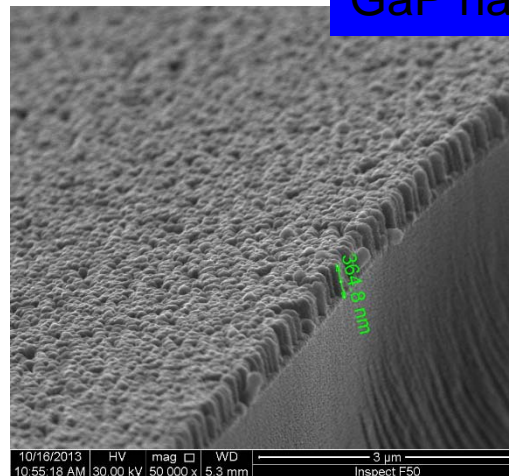
GaP nanowires + 50 nm ZnO



GaP-MOVPE

ZnO-magnetron sputtering

GaP nanowires + 150 nm ZnO



- Original approach was used to prepare ZnO-GaP core-shell nanowires by combination of MOVPE epitaxial technology (IEE SAS) and subsequent ZnO thin layer deposition by magnetron sputtering deposition technique (FEI IEP)

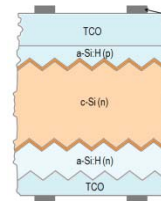
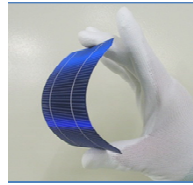
## Advanced PV technologies

1. Gen.: crystalline silicon



High performance  
Cell efficiency  
~25%

3. Gen.: amorphous/crystalline  
heterostructure



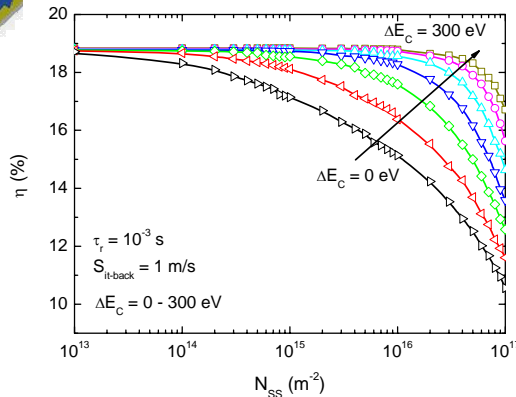
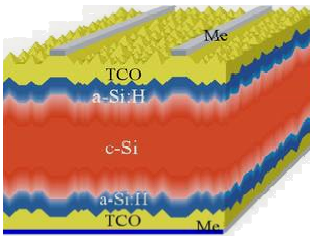
Low cost + High performance (~ 23%)

2. Gen.: amorphous silicon

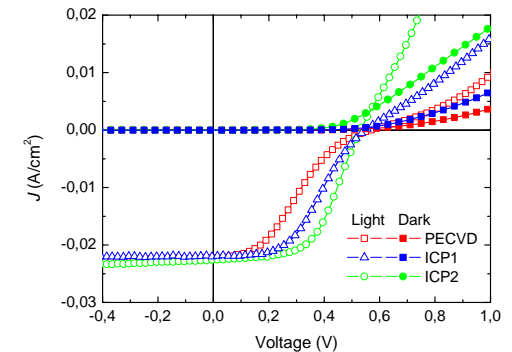
Low cost  
Cell efficiency  
~ 13%



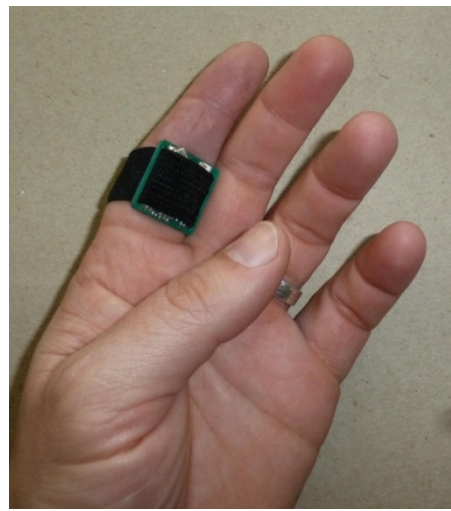
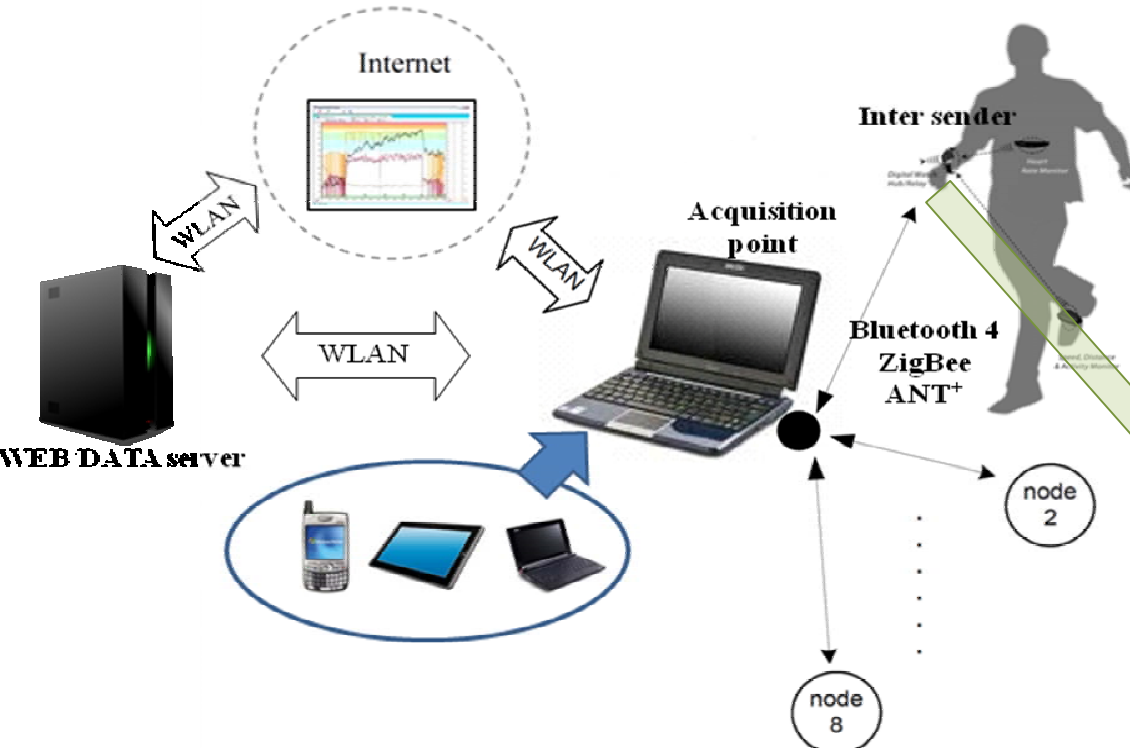
## Simulations (TCAD, Optic, Electric)



## Diagnostics (I-V, C-V-F...)



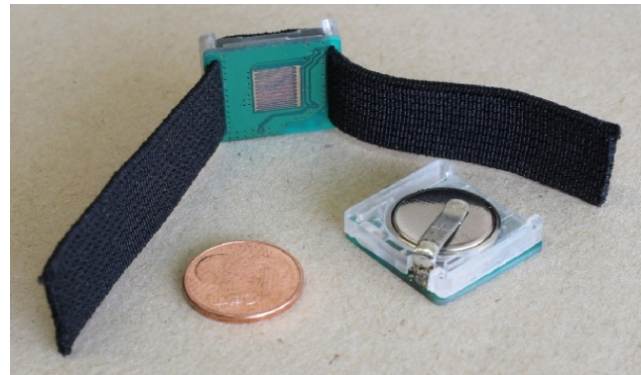
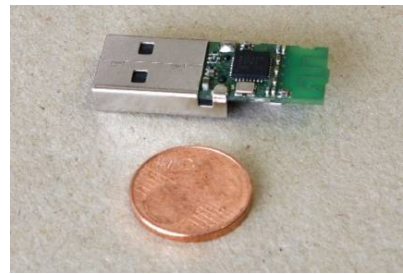
# SMART Electronic systems for wireless biomonitring



IDA microelectrode

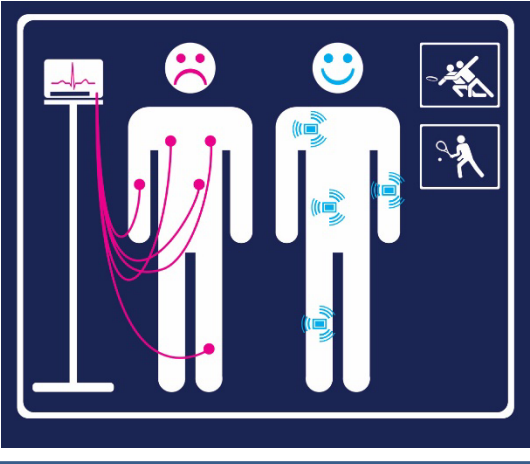
## Wireless on-body sensor (stress)

- attached to a finger
- IDA microelectrodes, special surface treatment
- USB dongle communicator
- rf energy effective communication



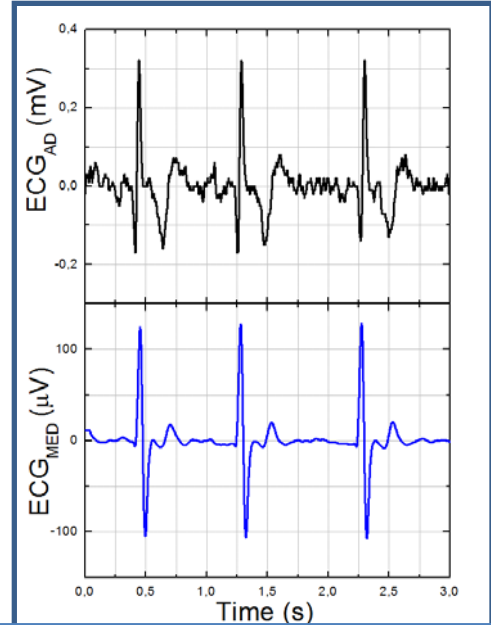
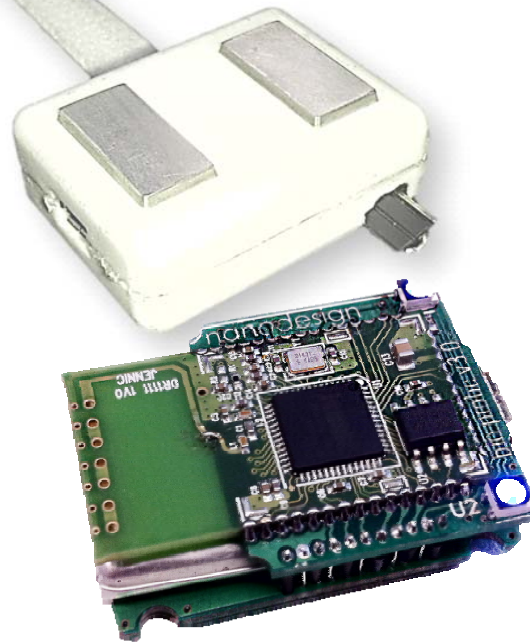
# SMART Electronic systems for health and fitness applications

Wireless biosensing  
applications

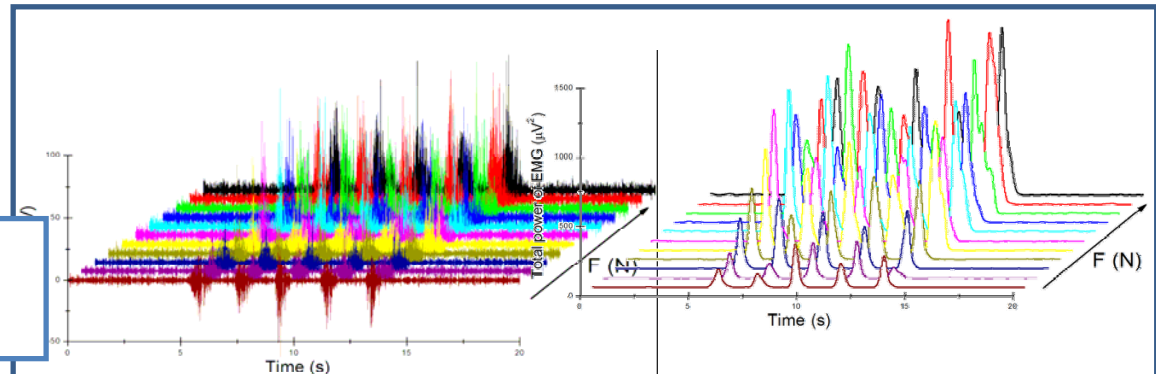


Total power of muscles  
EMG during fitness

ECG sensing probe  
design and electronics



Raw and filtered heart-  
rate signal measured  
by wireless system





## for health and fitness applications

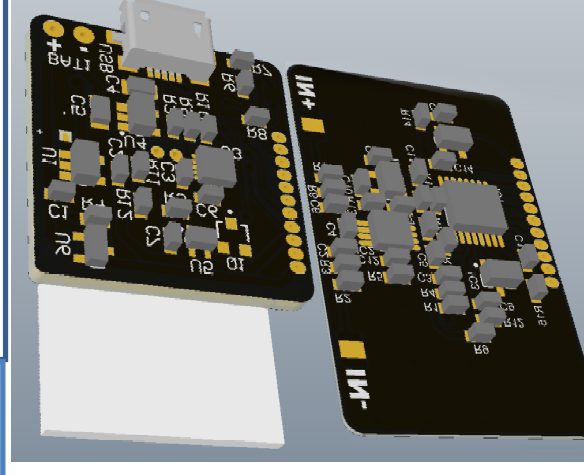
Forceplate “seven” for rehab- and diagnostic purposes developed in our labs



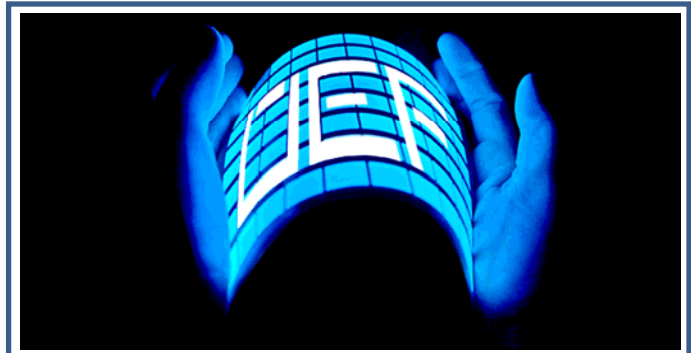
SMART devices serve the research in field of assisted healthcare



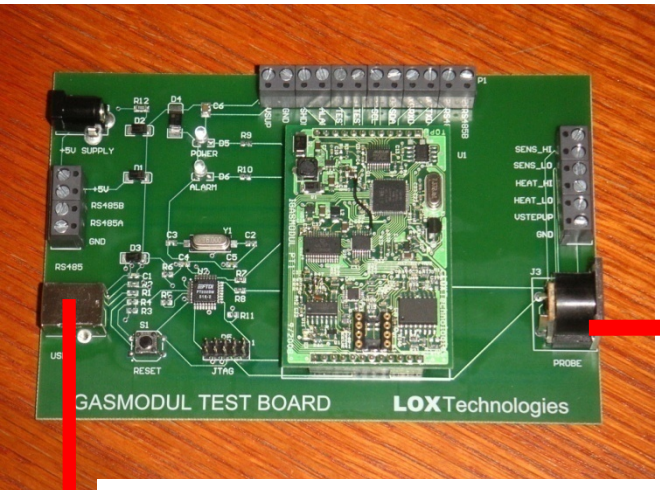
Intensive miniaturization of developed devices by each 6 months



Flexible clothing with flexible probes covered by organic semiconductor film for better performance

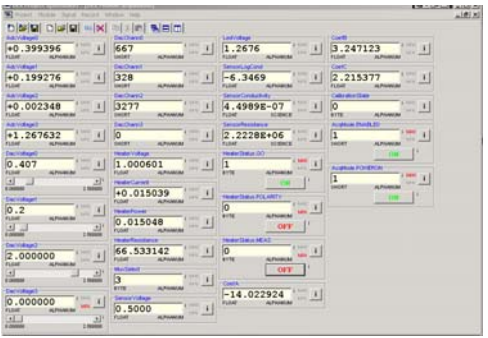


Organic semiconductor research in field of health bio-applications



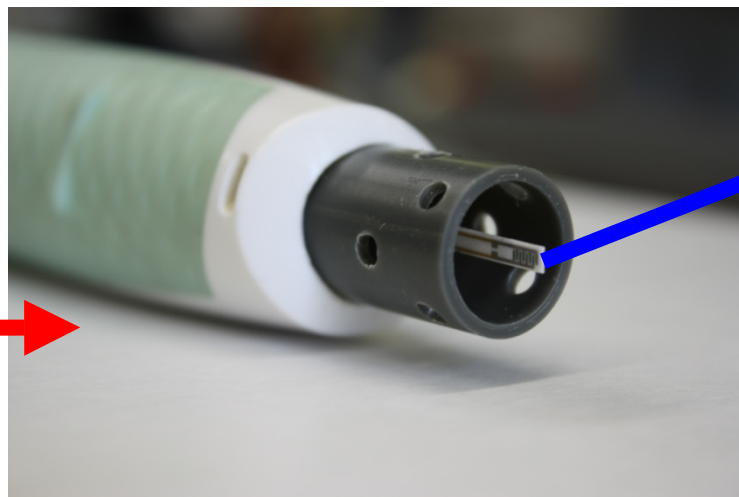
Control and measuring system

PC

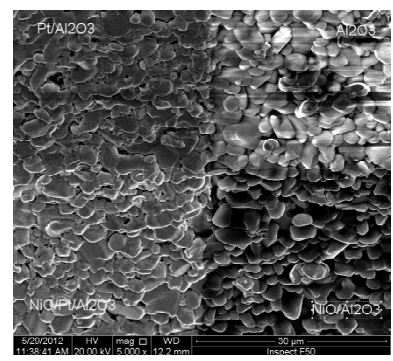
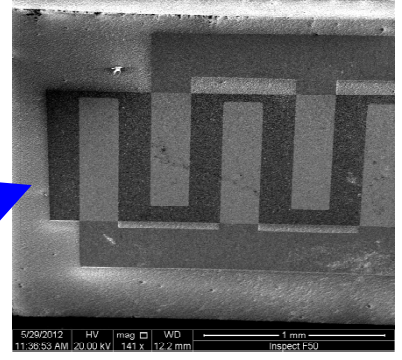


### Detection of gases:

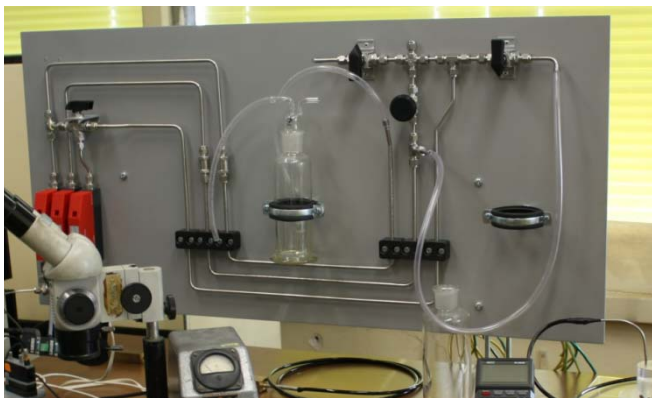
- NO<sub>2</sub> 10 ppm
- CO 150 ppm
- NH<sub>3</sub> 100 ppm
- H<sub>2</sub> 500 ppm
- CH<sub>4</sub>, ethanol, acetone



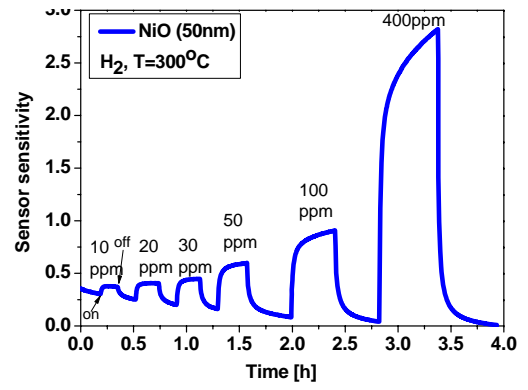
Gas sensing system



### Nanostructured surface

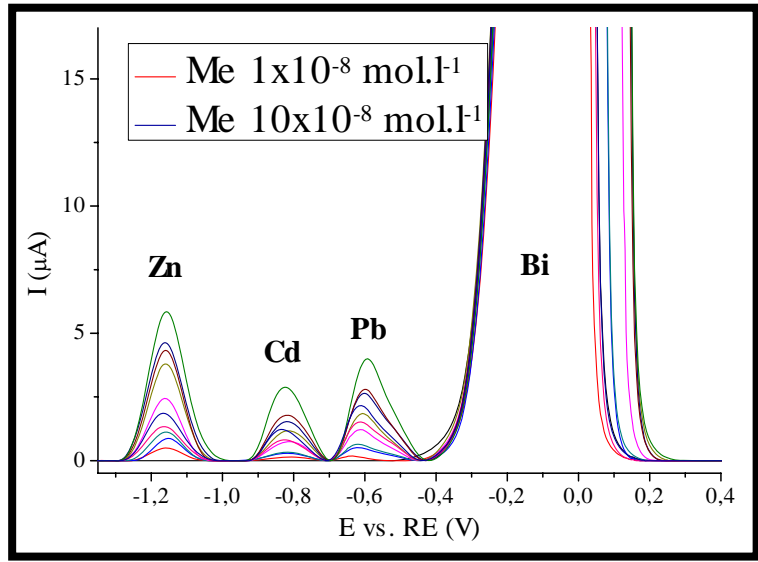
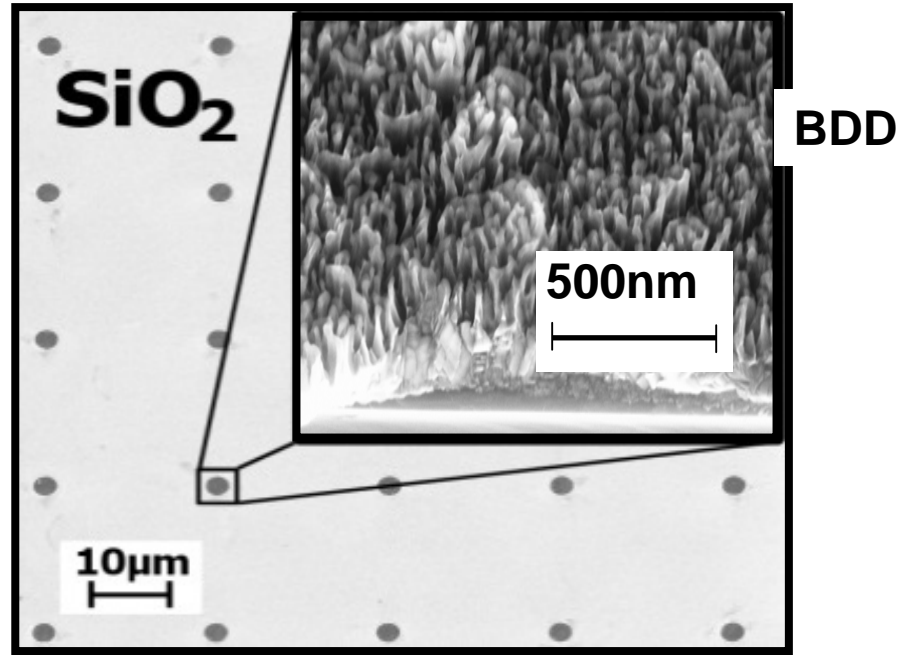


Gas calibration system

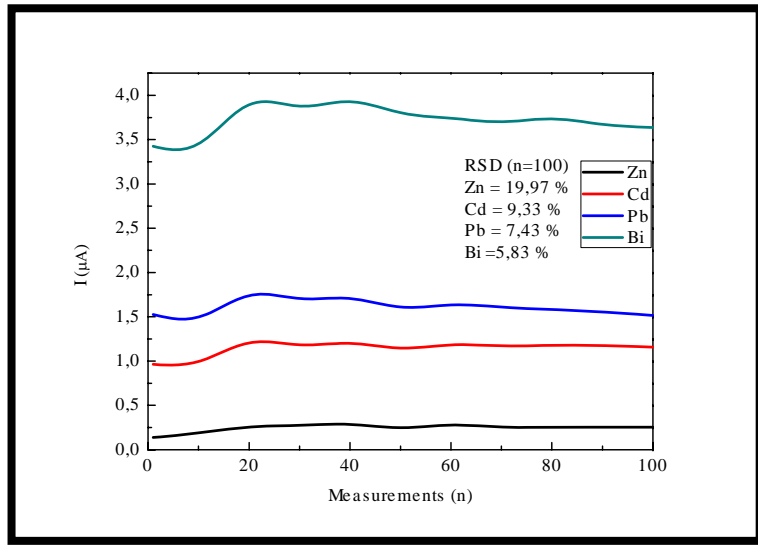


Hydrogen testing

# Nanostructured boron doped diamond for sensing heavy metals



B/C [ppm]	Ion	Sensitivity [nA.nmol <sup>-1</sup> .l.mm <sup>-2</sup> ]	R <sup>2</sup>	LOD (ppb)
10 000	Pb	20.84	0.999	2.58
	Cd	26.14	0.999	2.05
	Zn	19.86	0.996	4.18



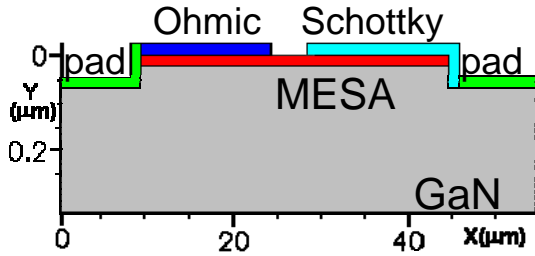
Results:

- Ultra low detection limit (nmol.l<sup>-1</sup>)
- High sensitivity
- High selectivity (simultaneous detection of Cd, Zn, Pb)
- High repeatability of measurements

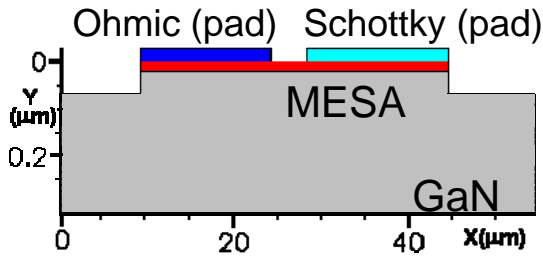
Max. conc. in water: c(Pb) = 20 µg/l,  
c(Cd) = 5 µg/l, c(Zn) = 100 µg/l

# Analysis of the leakage current of AlGaN/GaN Schottky diode dependent on ohmic contact pad electrode position

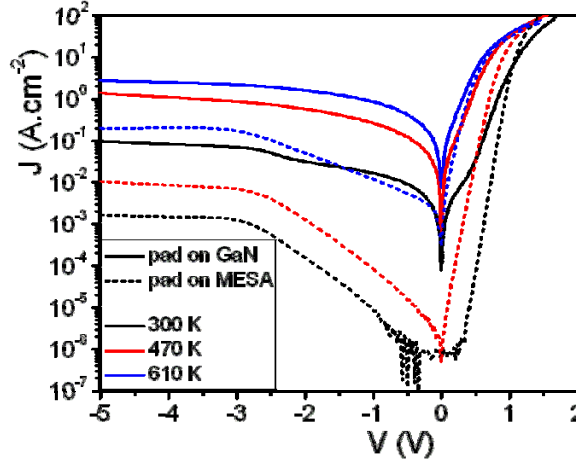
pad on GaN



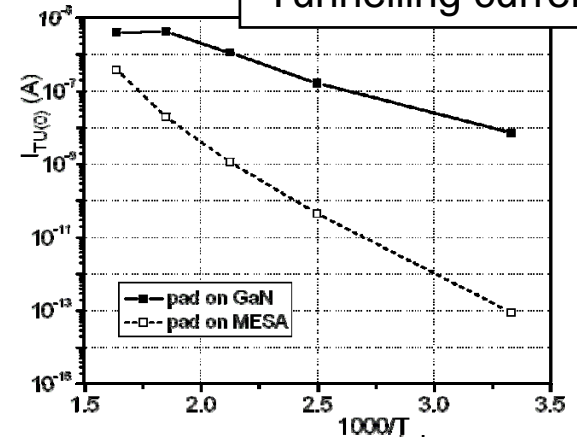
pad on MESA



Experimental I-V characteristics

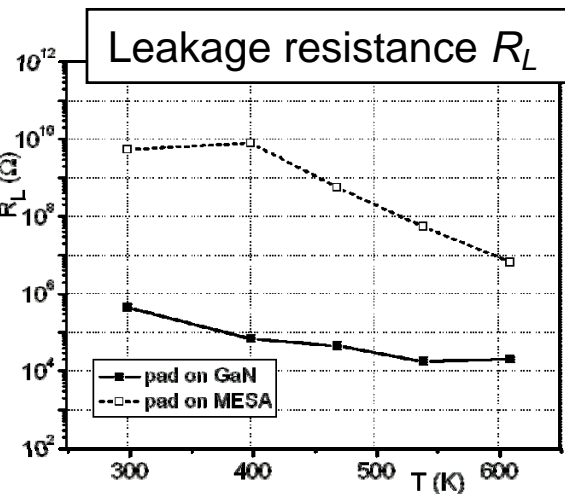


Tunnelling current

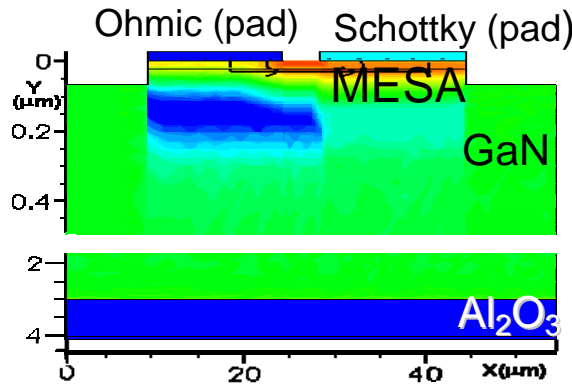


2-D simulation results -

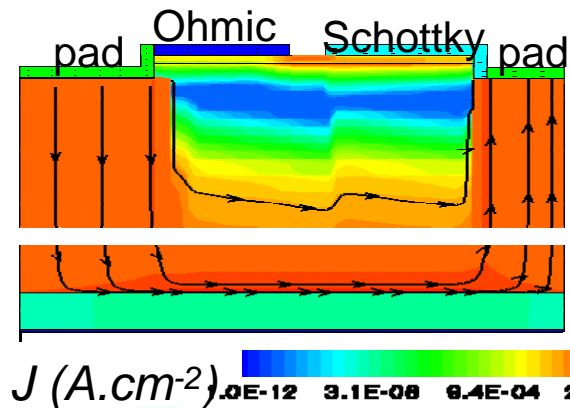
Current density distribution at  $V_{SK} = -3$  V



pad on MESA



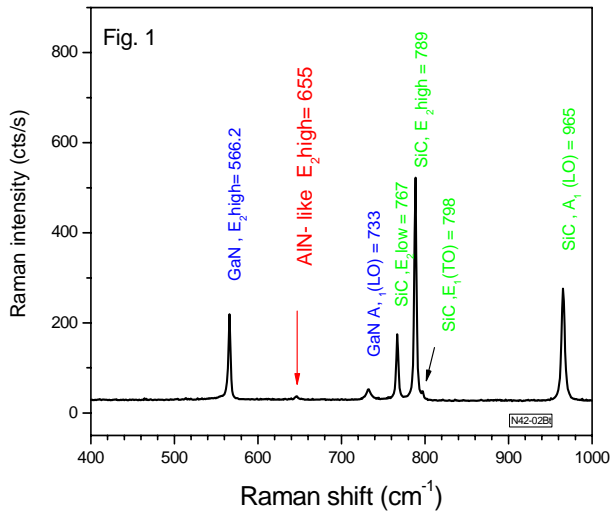
pad on GaN



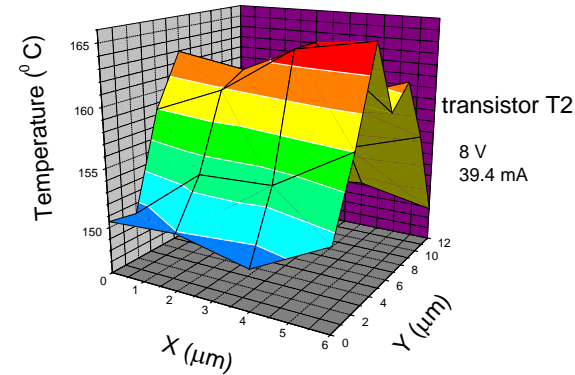
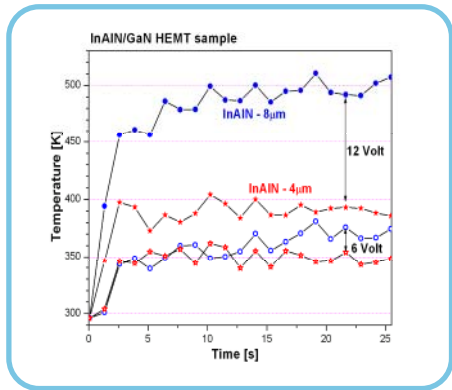
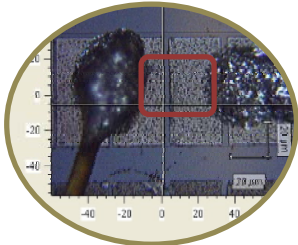
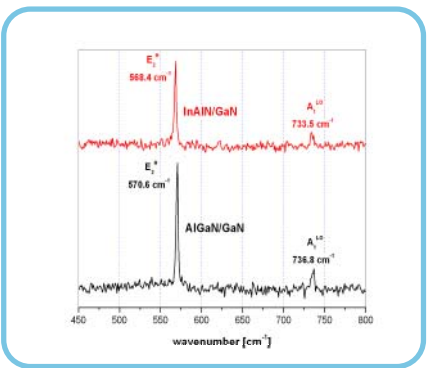
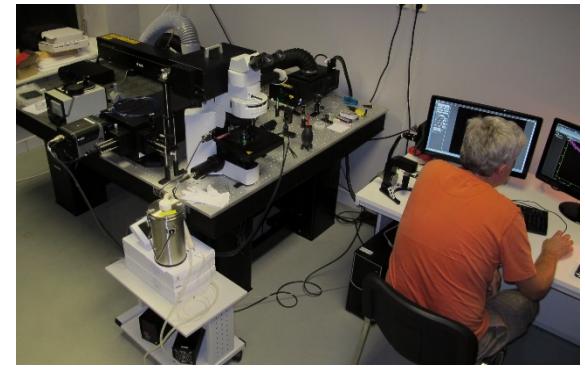
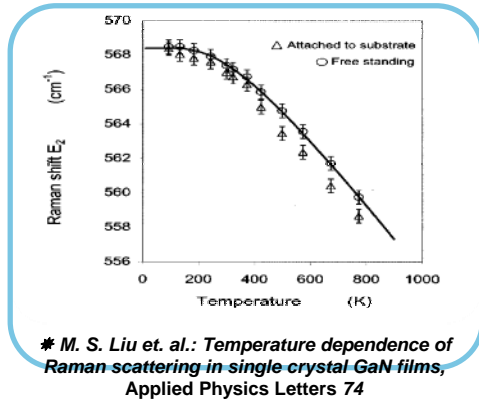
## Micro-Raman spectroscopy and PL system,

MonoVista CRS 75A|BX51, ( 300 – 1050 nm), Spectroscopy&Imaging (S&I), Germany  
UV- VIS- NIR konfocal Raman microscope. Excitation lasers: He-Cd 325 nm, Ar -tunable 488&514 nm

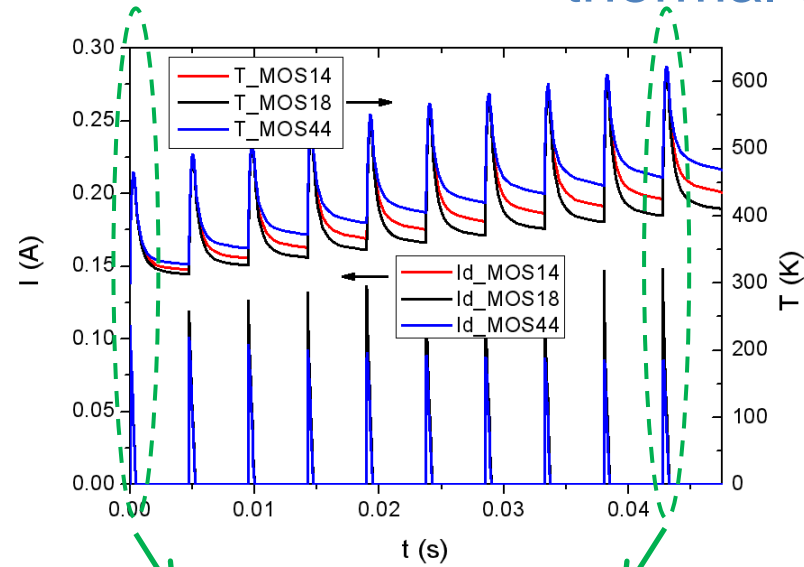
### InAlN/GaN/AlN/SiC - HEMT



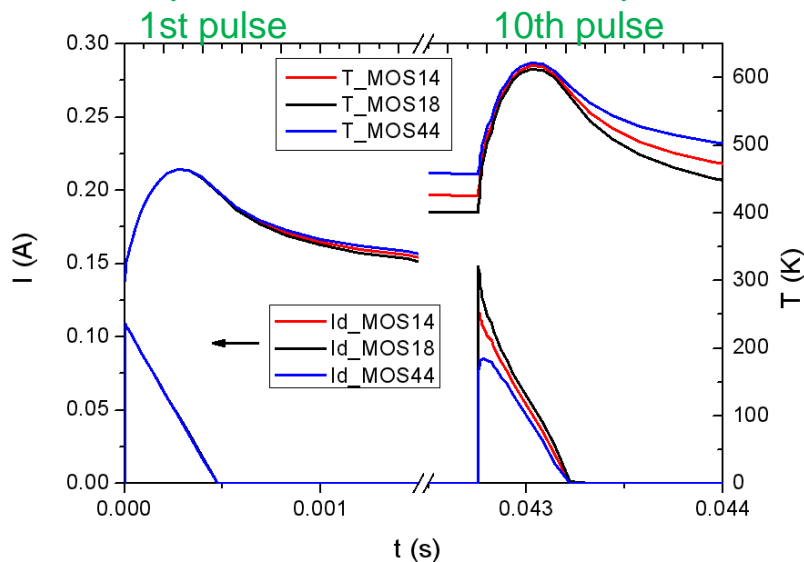
### Thermal assessment (micro Raman spectroscopy)



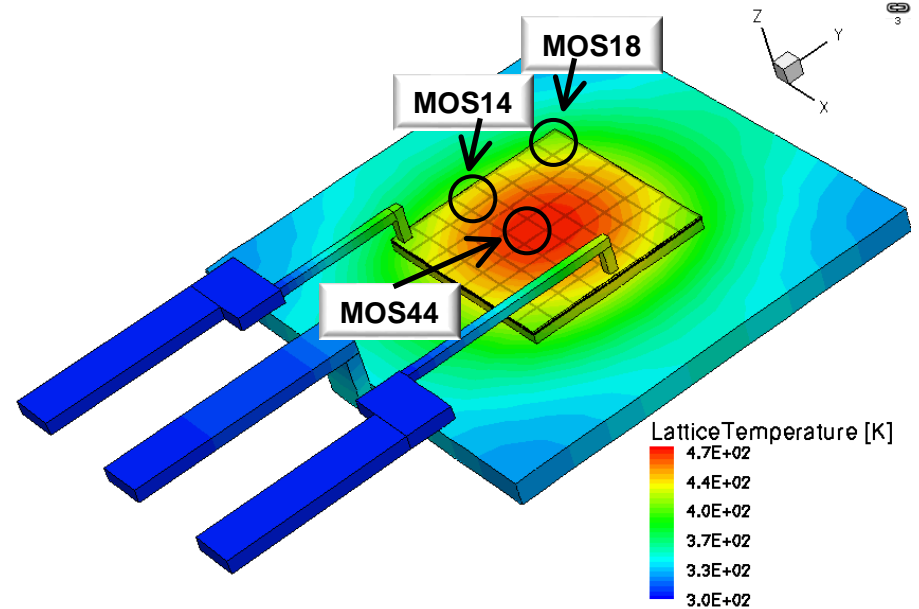
## Interaction between SDEVICE and HSPICE for electro-thermal circuit simulations



Temperature (T) and drain current (I) for selected MOSFET parts during 10 UIS pulses



Structure temperature distribution



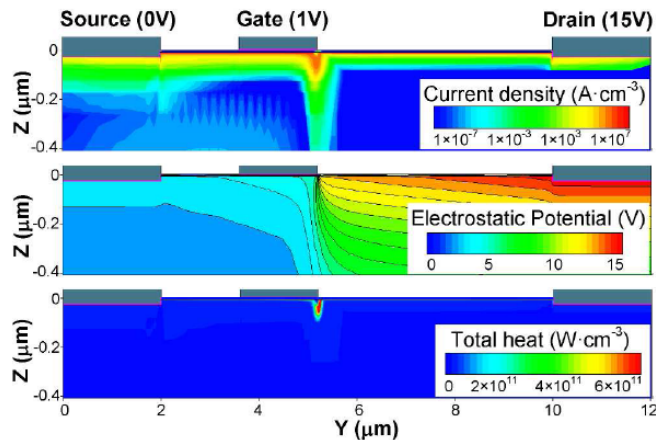
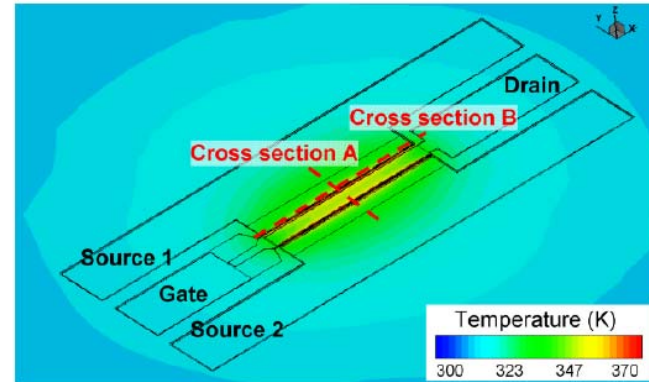
3-D distributed parameters of the MOSFET are taken in to account

# HEMT 3-D MIXED-MODE ELECTROTHERMAL SIMULATION

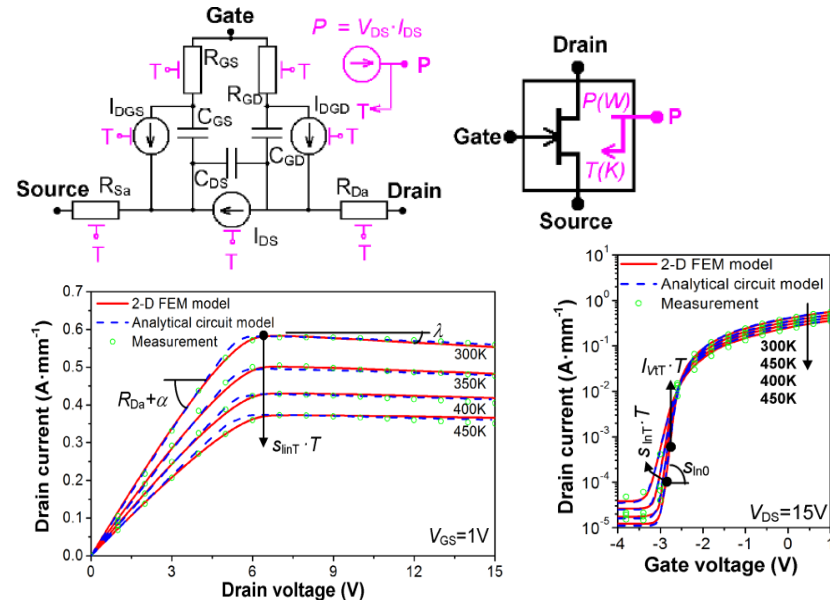
- > TCAD tools (Synopsys Sentaurus)
- > Electro-thermal SPICE model of HEMT

Done work:

- prepared 2D and 3D calibrated TCAD models
- 2-D FEM electrothermal simulations
- temperature dependent analytical circuit model
- 3-D mixed-mode electrothermal simulation



Current density, electrostatic potential, and total heat distribution during on-state operating conditions. Most of the generated heat is located under the drain side of the gate edge.

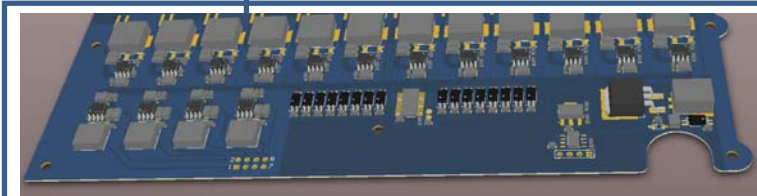
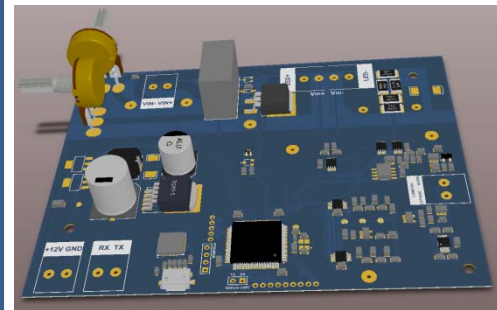
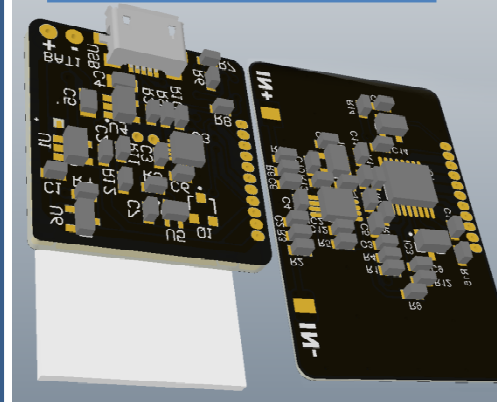


# SMART Electronic systems for general control of illumination

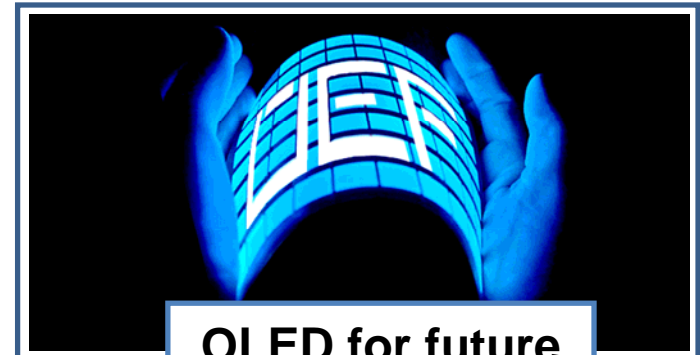
New lighting  
modules



Drivers and  
control units



SMART Control unit  
for >50 modules



OLED for future  
luminance

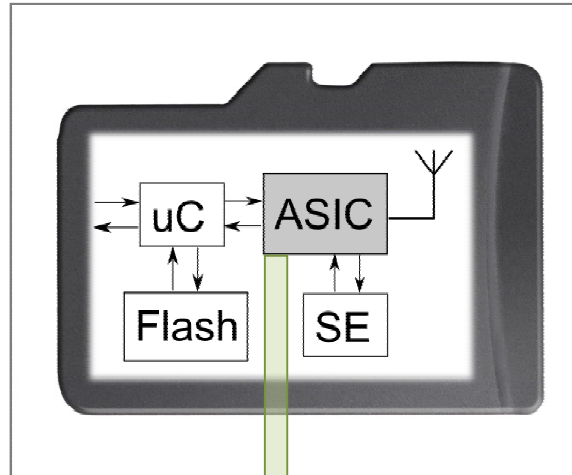
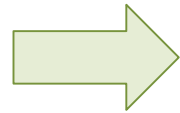
OMS



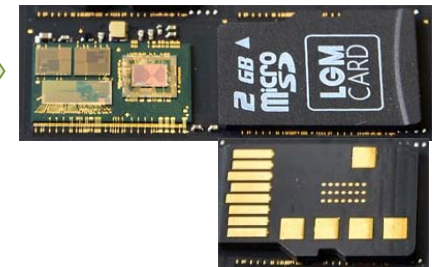
# SMART Integrated systems for mobile payment



contactless  
mobile payment



3D integrated system  
in a MicroSD card

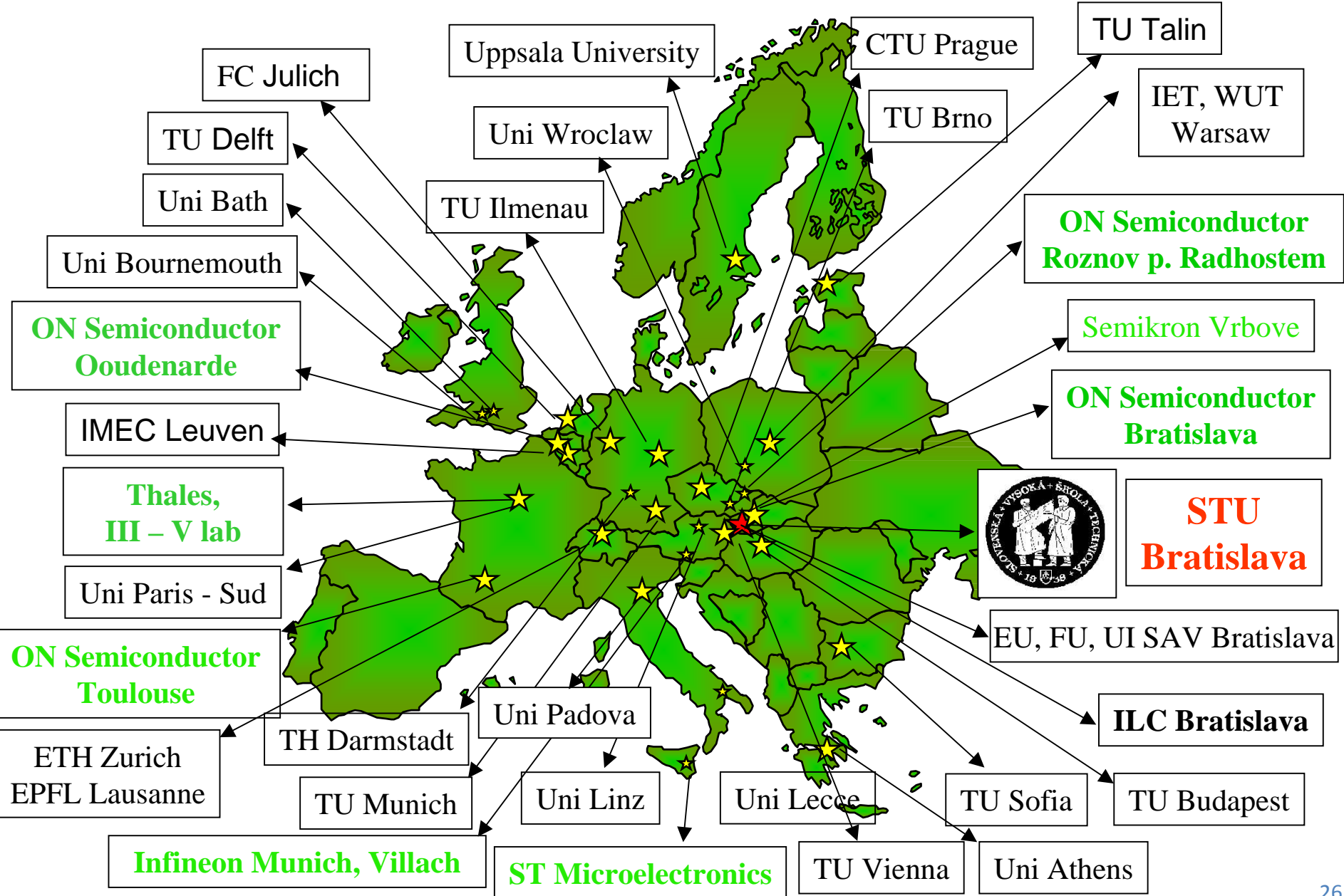


## Communication ASIC :

- 4x4 mm
- CMOS 0,35  $\mu\text{m}$
- 90  $\mu\text{m}$  substrate thickness
- mixed-signal (analog, digital, RF)

Technology transfer  $\Rightarrow$  R-DAS  $\Rightarrow$  Logomotion

# Partnership of Institute of Electronics and Photonics FEI STU



## 7 FP Projects

- MORGaN – IP (III-V lab, Alcatel-Thales)
- SMAC - IP (ST Microelectronics)
- IDESA, IDESA 2 - CSA (IMEC)
- EURO-DOTS, EURO-DOTS 2 - CSA (IMEC)
- Guardian Angels - FET Flagship (EPFL, ETH)
- Albatross – Marie Currie (Tyndall)

### *1<sup>st</sup> Horizon 2020 project*

- INREP (Uni Bath)

### *1<sup>st</sup> ECSEL projects*

- PowerBase (Infineon)
- Osiris (III-V lab)

## ENIAC JU Projects

- END (ON Semiconductor)
- MAS (Infineon)
- ERG (ST Microelectronics)
- E2SG (Infineon)
- E2COGaN (ON Semiconductor)
- eRamp (Infineon)
- SafeSens (NXP)

## Staff Members

- **10 Full + 10 Associate Professors**
- **18 Postdocs under 35 Years**
- **8 Engineers (before defence of PhD)**
- **about 30 PhD Students**

# Collaboration, Technology Transfer

## SME's

- NanoDesign, POWERTEC, R-DAS - spin off
- Logomotion, Lox-Technologies, Sylex, ARETA Pro, Applied Precision, Danubia Nanotech

## Large Enterprise

- OMS (one of the top leading companies in lighting modules in Europe)
- ON Semiconductor (BDC)
- Samsung
- ST Microelectronics
- Infineon
- Semikron

## Research Institutes – exploitation of complementary tools and methods

- International Laser Centre
- Institute of Electrical Engineering of SAS
- Institute of Informatics of SAS
- Faculty of Natural Sciences Comenius University

- **Quality of life (SMART sensors)**
  - Health, ageing society
  - Wellness, sport
  - Environmental monitoring
- **Low power analogue/mixed/rf IC's and systems design...**
- **New materials** (organic materials, c-nanotubes, graphen, metal oxides, wide bandgap semiconductors)
- **Organic electronics**
- **Energy harvesting (photovoltaics)**
- **Smart power devices (SJ FET, GaN, ...)**
- **Smart sensors**
- **LED/OLED lighting control (industrial electronics)**
- **Photonics.....**

# Conclusions

- **Long term involvement of IEP FEI STU in KET fields**
  - experienced staff with very good physical background
  - well equipped laboratories
- **Frequent and fruitful national and international collaboration (FP 7, ENIAC JU, HORIZON 2020...)**
- **Large team of experienced researchers combined with enthusiastic young experts and PhD students**
- **Scientific school in Micro/Nano - Electronics and Photonics at STU Bratislava** – implementation of new knowledge and obtained results in related curricula, education of new young experts

**The effort, enthusiasms and  
continual support of the institute  
crew is greatly appreciate**

**Thank you for  
your attention**